Single D-type flip-flop with set and reset; positive edge trigger Rev. 3 — 3 October 2018

1. General description

The 74LVC2G74-Q100 is a single positive-edge triggered D-type flip-flop. It has individual data (D) inputs, clock (CP) inputs, set (\overline{SD}) and reset (\overline{RD}) inputs, and complementary Q and \overline{Q} outputs.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing damaging backflow current through the device when it is powered down.

The set and reset are asynchronous active LOW inputs and operate independently of the clock input. Information on the data input is transferred to the Q output on the LOW-to-HIGH transition of the clock pulse. The D inputs must be stable, one set-up time prior to the LOW-to-HIGH clock transition for predictable operation. Schmitt trigger action at all inputs makes the circuit highly tolerant to slower input rise and fall times.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)

 Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 1.65 V to 5.5 V
- 5 V tolerant inputs for interfacing with 5 V logic
- High noise immunity
- Complies with JEDEC standard:
- JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8-B/JESD36 (2.7 V to 3.6 V)
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- ±24 mA output drive (V_{CC} = 3.0 V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V

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3. Ordering information

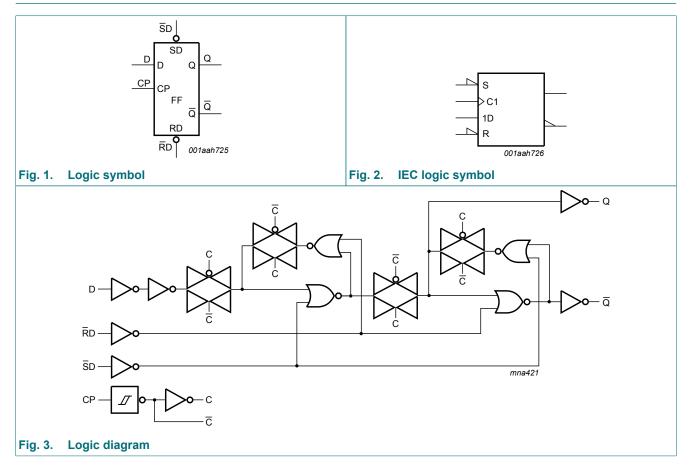
Type number	Package							
	Temperature range	Name	Description	Version				
74LVC2G74DP-Q100	-40 °C to +125 °C	TSSOP8	plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm	SOT505-2				
74LVC2G74DC-Q100	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1				

4. Marking

Table 2. Marking codes	
Type number	Marking code [1]
74LVC2G74DP-Q100	V74
74LVC2G74DC-Q100	V74

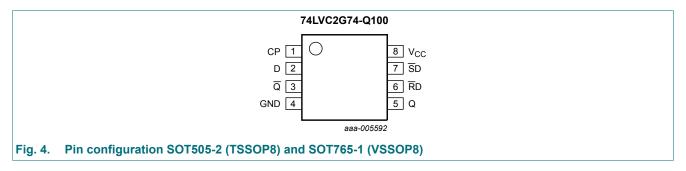
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description		
Symbol	Pin	Description
СР	1	clock input (LOW-to-HIGH, edge-triggered)
D	2	data input
Q	3	complement output
GND	4	ground (0 V)
Q	5	true output
RD	6	asynchronous reset-direct input (active LOW)
SD	7	asynchronous set-direct input (active LOW)
V _{CC}	8	supply voltage

7. Functional description

Table 4. Function table for asynchronous operation

H = *HIGH* voltage level; *L* = *LOW* voltage level; *X* = don't care.

Input				Output		
SD	RD	СР	D	Q	Q	
L	Н	Х	Х	Н	L	
Н	L	Х	Х	L	Н	
L	L	Х	Х	Н	Н	

Table 5. Function table for synchronous operation

H = HIGH voltage level; L = LOW voltage level; $\uparrow = LOW$ -to-HIGH CP transition;

 Q_{n+1} = state after the next LOW-to-HIGH CP transition.

				Output		
SD	RD	СР	D	Q _{n+1}	Q _{n+1}	
Н	Н	1	L	L	Н	
Н	Н	1	Н	Н	L	

8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+6.5	V
I _{IK}	input clamping current	V _I < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+6.5	V
I _{OK}	output clamping current	$V_{\rm O}$ > $V_{\rm CC}$ or $V_{\rm O}$ < 0 V		-	±50	mA
Vo	output voltage	Active mode	[1]	-0.5	V _{CC} + 0.5	V
		Power-down mode; V_{CC} = 0 V	[1]	-0.5	+6.5	V
I _O	output current	$V_{O} = 0 V \text{ to } V_{CC}$		-	±50	mA
I _{CC}	supply current			-	100	mA
I _{GND}	ground current			-100	-	mA
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[2]	-	300	mW
T _{stg}	storage temperature			-65	+150	°C

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For TSSOP8 packages: above 55 °C the value of P_{tot} derates linearly with 2.5 mW/K.

For VSSOP8 packages: above 110 °C the value of Ptot derates linearly with 8.0 mW/K.

9. Recommended operating conditions

Table 7. Operating conditions

Symbol	Parameter	arameter Conditions		Max	Unit
V _{CC}	supply voltage		1.65	5.5	V
VI	input voltage		0	5.5	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	5.5	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 1.65 V to 2.7 V	-	20	ns/V
		V _{CC} = 2.7 V to 5.5 V	-	10	ns/V

10. Static characteristics

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	T _{amb} =	-40 °C to	+85 °C	T _{an} -40 °C to	Unit	
			Min	Тур <mark>[1]</mark>	Max	Min	Мах	1
VIH	HIGH-level	V _{CC} = 1.65 V to 1.95 V	0.65V _{CC}	-	-	0.65V _{CC}	-	V
	input voltage	V _{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	V
		V _{CC} = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
		V _{CC} = 4.5 V to 5.5 V	0.7V _{CC}	-	-	0.7V _{CC}	-	V
VIL	LOW-level	V _{CC} = 1.65 V to 1.95 V	-	-	0.35V _{CC}	-	0.35V _{CC}	V
	input voltage	V _{CC} = 2.3 V to 2.7 V	-	-	0.7	-	0.7	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
		V _{CC} = 4.5 V to 5.5 V	-	-	0.3V _{CC}	-	0.3V _{CC}	V
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}						
	output voltage	I _O = -100 μA; V _{CC} = 1.65 V to 5.5 V	V _{CC} - 0.1	-	-	V _{CC} - 0.1	-	V
		I _O = -4 mA; V _{CC} = 1.65 V	1.2	1.54	-	0.95	-	V
		I _O = -8 mA; V _{CC} = 2.3 V	1.9	2.15	-	1.7	-	V
		I _O = -12 mA; V _{CC} = 2.7 V	2.2	2.50	-	1.9	-	V
		I _O = -24 mA; V _{CC} = 3.0 V	2.3	2.62	-	2.0	-	V
		I _O = -32 mA; V _{CC} = 4.5 V	3.8	4.11	-	3.4	-	V
V _{OL}	LOW-level	V _I = V _{IH} or V _{IL}						
	output voltage	I _O = 100 μA; V _{CC} = 1.65 V to 5.5 V	-	-	0.10	-	0.10	V
		I _O = 4 mA; V _{CC} = 1.65 V	-	0.07	0.45	-	0.70	V
		I _O = 8 mA; V _{CC} = 2.3 V	-	0.12	0.30	-	0.45	V
		I _O = 12 mA; V _{CC} = 2.7 V	-	0.17	0.40	-	0.60	V
		I _O = 24 mA; V _{CC} = 3.0 V	-	0.33	0.55	-	0.80	V
		I _O = 32 mA; V _{CC} = 4.5 V	-	0.39	0.55	-	0.80	V
I	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	±0.1	±1	-	±1	μA
I _{OFF}	power-off leakage current	$V_{I} \text{ or } V_{O} = 5.5 \text{ V}; V_{CC} = 0 \text{ V}$	-	±0.1	±2	-	±2	μA
I _{CC}	supply current	V _I = 5.5 V or GND; V _{CC} = 1.65 V to 5.5 V; I _O = 0 A	-	0.1	4	-	4	μA
ΔI _{CC}	additional supply current	per pin; V ₁ = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 2.3 V to 5.5 V	-	5	500	-	500	μA
CI	input capacitance		-	4.0	-	-	-	pF

[1] All typical values are measured at T_{amb} = 25 °C.

11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 7.

Symbol	Parameter	Conditions	T _{amb} :	= -40 °C to ·	+85 °C	T _{ar} -40 °C to	_{nb} = o +125 °C	Unit
			Min	Typ [1]	Мах	Min	Max	-
t _{pd}	propagation delay	CP to Q, \overline{Q} ; see Fig. 5 [2]						
		V _{CC} = 1.65 V to 1.95 V	1.5	6.0	13.4	1.5	13.4	ns
		V _{CC} = 2.3 V to 2.7 V	1.0	3.5	7.1	1.0	7.1	ns
		V _{CC} = 2.7 V	1.0	3.5	7.1	1.0	7.1	ns
		V _{CC} = 3.0 V to 3.6 V	1.0	3.5	5.9	1.0	5.9	ns
		V _{CC} = 4.5 V to 5.5 V	1.0	2.5	4.1	1.0	4.1	ns
		\overline{SD} to Q, \overline{Q} ; see <u>Fig. 6</u> [2]						
		V _{CC} = 1.65 V to 1.95 V	1.5	6.0	12.9	1.5	12.9	ns
		V _{CC} = 2.3 V to 2.7 V	1.0	3.5	7.0	1.0	7.0	ns
		V _{CC} = 2.7 V	1.0	3.5	7.0	1.0	7.0	ns
		V _{CC} = 3.0 V to 3.6 V	1.0	3.0	5.9	1.0	5.9	ns
		V _{CC} = 4.5 V to 5.5 V	1.0	2.5	4.1	1.0	4.1	ns
		\overline{RD} to Q, \overline{Q} ; see <u>Fig. 6</u> [2]						
		V _{CC} = 1.65 V to 1.95 V	1.5	5.0	12.9	1.5	12.9	ns
		V _{CC} = 2.3 V to 2.7 V	1.0	3.5	7.0	1.0	7.0	ns
		V _{CC} = 2.7 V	1.0	3.5	7.0	1.0	7.0	ns
		V _{CC} = 3.0 V to 3.6 V	1.0	3.0	5.9	1.0	5.9	ns
		V _{CC} = 4.5 V to 5.5 V	1.0	2.5	4.1	1.0	4.1	ns
t _W	pulse width	CP HIGH or LOW; see Fig. 5						
		V _{CC} = 1.65 V to 1.95 V	6.2	-	-	6.2	-	ns
		V _{CC} = 2.3 V to 2.7 V	2.7	-	-	2.7	-	ns
		V _{CC} = 2.7 V	2.7	-	-	2.7	-	ns
		V _{CC} = 3.0 V to 3.6 V	2.7	1.3	-	2.7	-	ns
		V _{CC} = 4.5 V to 5.5 V	2.0	-	-	2.0	-	ns
		SD and RD LOW; see Fig. 6						
		V _{CC} = 1.65 V to 1.95 V	6.2	-	-	6.2	-	ns
		V _{CC} = 2.3 V to 2.7 V	2.7	-	-	2.7	-	ns
		V _{CC} = 2.7 V	2.7	-	-	2.7	-	ns
		V _{CC} = 3.0 V to 3.6 V	2.7	1.6	-	2.7	-	ns
		V _{CC} = 4.5 V to 5.5 V	2.0	-	-	2.0	-	ns
t _{rec}	recovery time	SD or RD; see <u>Fig. 6</u>						
		V _{CC} = 1.65 V to 1.95 V	1.9	-	-	1.9	-	ns
		V _{CC} = 2.3 V to 2.7 V	1.4	-	-	1.4	-	ns
		V _{CC} = 2.7 V	1.3	-	-	1.3	-	ns
		V _{CC} = 3.0 V to 3.6 V	+1.2	-3.0	-	+1.2	-	ns
		V _{CC} = 4.5 V to 5.5 V	1.0	-	-	1.0	-	ns

Single D-type flip-flop with set and reset; positive edge trigger

Symbol	Parameter	Conditions	T _{amb} = -40 °C to +85 °C			T _{amb} = -40 °C to +125 °C		Unit
			Min	Typ [1]	Мах	Min	Max	-
t _{su}	set-up time	D to CP; see <u>Fig. 5</u>						
		V _{CC} = 1.65 V to 1.95 V	2.9	-	-	2.9	-	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	ns
		V _{CC} = 2.7 V	1.7	-	-	1.7	-	ns
		V _{CC} = 3.0 V to 3.6 V	1.3	0.5	-	1.3	-	ns
		V _{CC} = 4.5 V to 5.5 V	1.1	-	-	1.1	-	ns
t _h hold time	hold time	D to CP; see <u>Fig. 5</u>						
		V _{CC} = 1.65 V to 1.95 V	1.5	-	-	1.5	-	ns
		V _{CC} = 2.3 V to 2.7 V	1.0	-	-	1.0	-	ns
		V _{CC} = 2.7 V	1.0	-	-	1.0	-	ns
		V _{CC} = 3.0 V to 3.6 V	1.0	0.6	-	1.0	-	ns
		V _{CC} = 4.5 V to 5.5 V	1.0	-	-	1.0	-	ns
f _{max}	maximum	CP; see <u>Fig. 5</u>						
	frequency	V _{CC} = 1.65 V to 1.95 V	80	-	-	80	-	MHz
		V _{CC} = 2.3 V to 2.7 V	175	-	-	175	-	MHz
		V _{CC} = 2.7 V	175	-	-	175	-	MHz
		V _{CC} = 3.0 V to 3.6 V	175	280	-	175	-	MHz
		V _{CC} = 4.5 V to 5.5 V	200	-	-	200	-	MHz
C _{PD}	power dissipation capacitance	$V_{I} = GND \text{ to } V_{CC}; V_{CC} = 3.3 \text{ V}$ [3]	-	15	-	-	-	pF

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.

[2] t_{pd} is the same as t_{PLH} and t_{PHL} . [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_0)$ where:

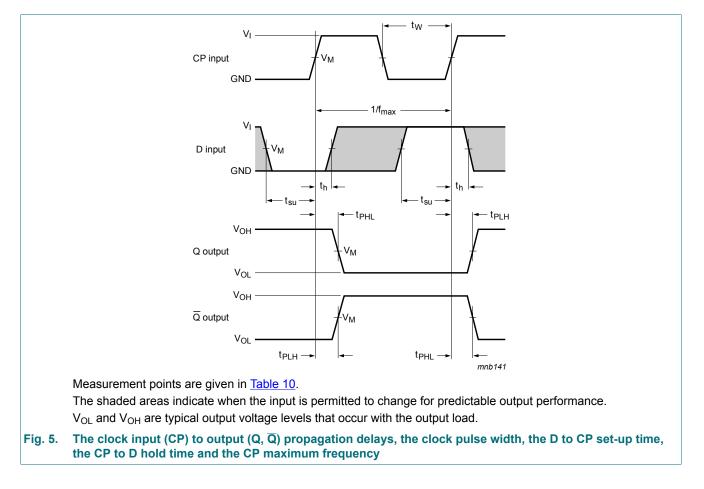
 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

 C_{L} = output load capacitance in pF;

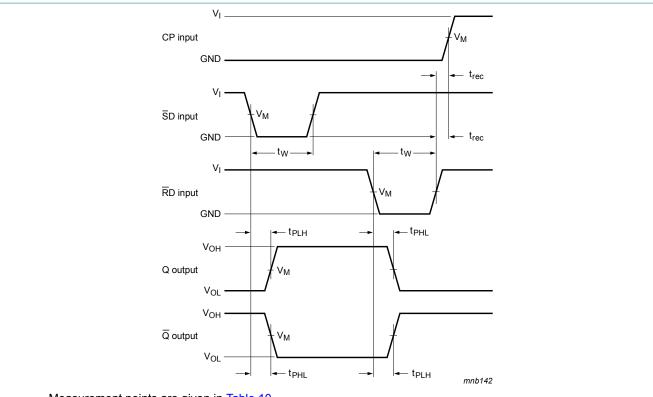
V_{CC} = supply voltage in V;

N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of outputs.



11.1. Waveforms and test circuit

74LVC2G74_Q100



Single D-type flip-flop with set and reset; positive edge trigger

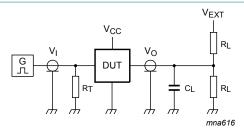
Measurement points are given in <u>Table 10</u>.

 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 6. The set (SD) and reset (RD) input to output (Q, Q) propagation delays, the set and reset pulse widths and the RD to CP recovery time

Table 10. Measurement points

Supply voltage	Input	Output	
V _{cc}	V _M	V _M	
1.65 V to 1.95 V	0.5 × V _{CC}	0.5 × V _{CC}	
2.3 V to 2.7 V	$0.5 \times V_{CC}$	0.5 × V _{CC}	
2.7 V	1.5 V	1.5 V	
3.0 V to 3.6 V	1.5 V	1.5 V	
4.5 V to 5.5 V	$0.5 \times V_{CC}$	0.5 × V _{CC}	



Test data is given in Table 11.

Definitions for test circuit:

R_L = Load resistance.

 C_{L} = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig. 7. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Input		Load	Load		V _{EXT}		
V _{cc}	VI	t _r , t _f	CL	RL	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}	
1.65 V to 1.95 V	V _{CC}	≤ 2.0 ns	30 pF	1 kΩ	open	GND	2V _{CC}	
2.3 V to 2.7 V	V _{CC}	≤ 2.0 ns	30 pF	500 Ω	open	GND	2V _{CC}	
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	GND	6 V	
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	GND	6 V	
4.5 V to 5.5 V	V _{CC}	≤ 2.5 ns	50 pF	500 Ω	open	GND	2V _{CC}	

12. Package outline

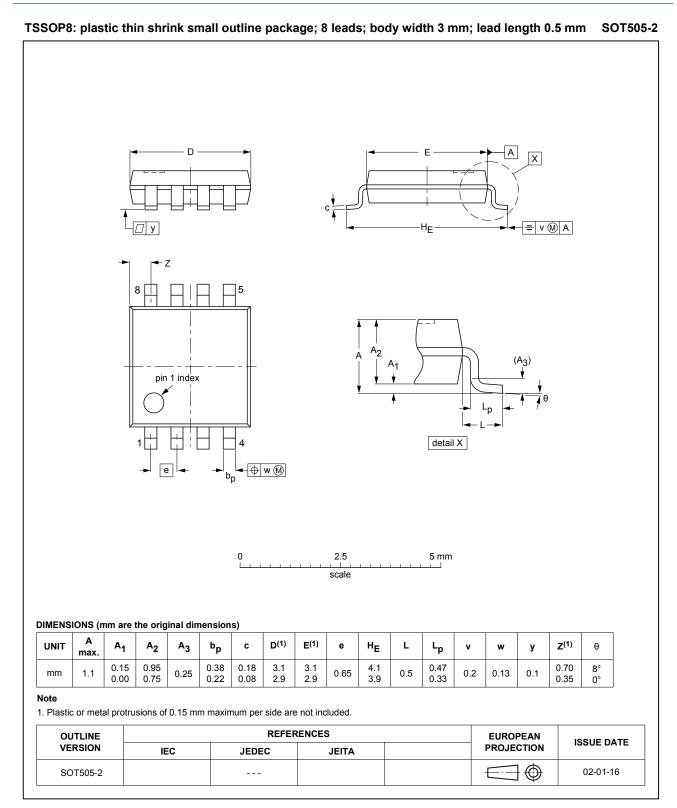
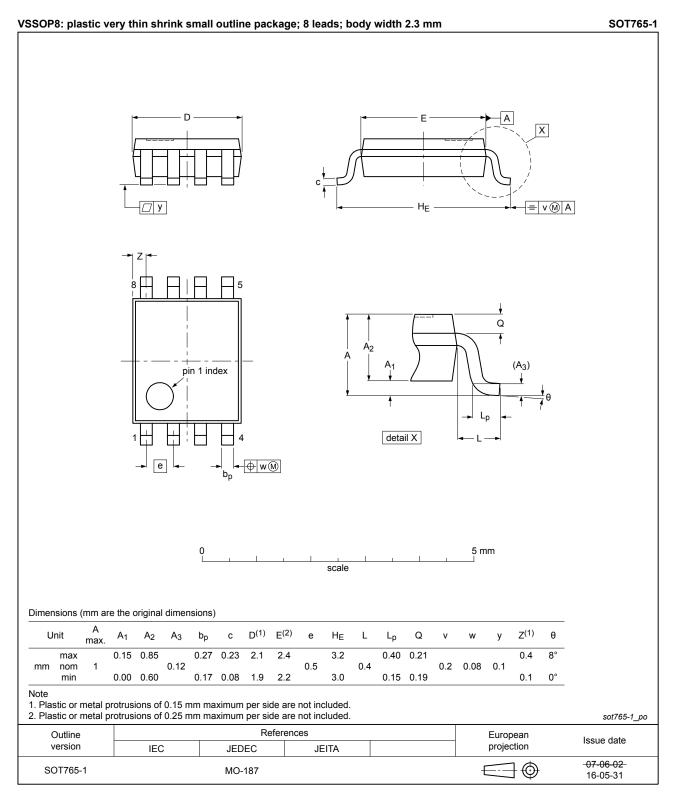


Fig. 8. Package outline SOT505-2 (TSSOP8)

74LVC2G74_Q100

Single D-type flip-flop with set and reset; positive edge trigger





13. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MIL	Military
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74LVC2G74_Q100 v.3	20181003	Product data sheet	-	74LVC2G74_Q100 v.2	
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. 				
74LVC2G74_Q100 v.2	20161214	Product data sheet	-	74LVC2G74_Q100 v.1	
Modifications:	• <u>Table 8</u> : The maximum limits for leakage current and supply current have changed.				
74LVC2G74_Q100 v.1	20121224	Product data sheet	-	-	

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

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